

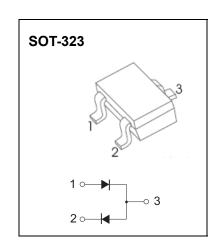
JIANGSU CHANGJIANG ELECTRONICS TECHNOLOGY CO., LTD

SOT-323 Plastic-Encapsulate Diodes

DAN217U SWITCHING DIODE

FEATURES

- Small surface mounting type
- Two diode elements are connected in series



MARKING:A7

Maximum Ratings and Electrical Characteristics, Single Diode @Ta=25 ℃

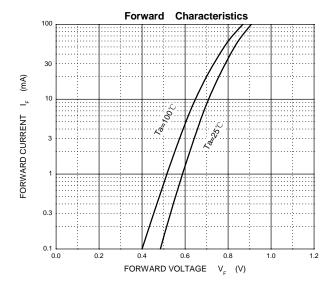
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Parameter	Symbol	Limit	Unit		
Peak reverse voltage	V _{RM}	80	V		
DC reverse voltage	V _R	80	V		
Maximum (peak) forward current	I _{FM}	300	mA		
Average forward current	Io	100	mA		
Surge current (1µs) (10ms)	I _{FSM}	400 1000	mA		
Power dissipation	P _D	200	mW		
Junction temperature	Tj	150	°C		
Storage temperature	T _{stg}	-55~+150	°C		
Operating temperature range	T _{opr}	-40~+100	℃		

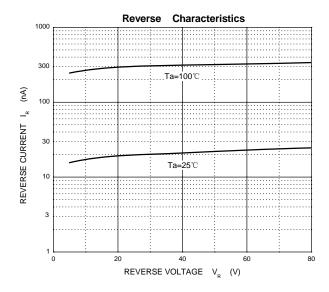
ELECTRICAL CHARACTERISTICS (Ta=25°C unless otherwise specified)

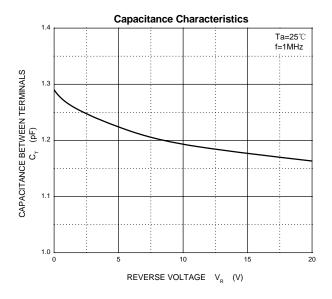
Parameter	Symbol	Test conditions	Min	Max	Unit
Reverse breakdown voltage	$V_{(BR)}$	I _R = 100μA	80		V
Reverse voltage leakage current	I _R	V _R =70V		0.2	μΑ
Forward voltage	V _F	I _F =100mA		1200	mV

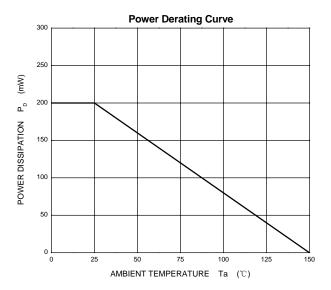
Typical Characteristics

DAN217U









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